

BAS70W / BAS70W-04 / BAS70W-05 / BAS70W-06

List

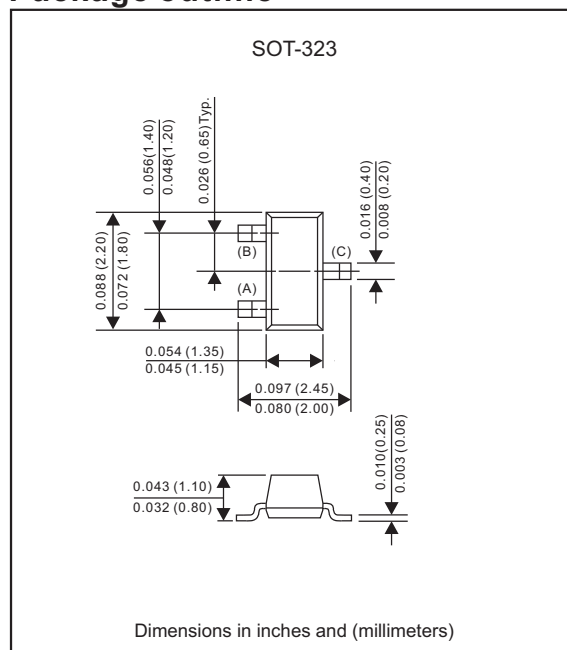
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BAS70W / BAS70W-04 / BAS70W-05 / BAS70W-06**70mA Surface Mount
Small Signal Schottky Diodes 70V****Features**

- Low current rectification and high speed switching.
- Tiny surface mount type.
- Up to 200mA current capability.
- Low forward voltage drop ($V_F = 1.00V$ typ. @15mA)
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts for green partner, exceeds environmental standards of MIL-STD-19500 /228
- High speed ($t_{rr} < 5$ ns)
- Suffix "-H" indicates Halogen-free part, ex.BAS70W-H.

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, SOT-323
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Mounting Position : Any
- Weight : Approximated 0.006 gram

Package outline**Maximum ratings and Electrical Characteristics** (AT $T_A = 25^\circ C$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Repetitive peak reverse voltage		V_{RRM}			70	V
Reverse voltage		V_R			70	V
Power dissipation		P_D			200	mW
Non-Repetitive Peak Forward Surge Current	$t_p < 8.3ms$	I_{FSM}			100	mA
Forward current		I_F			70	mA
Junction temperature		T_J	-55		+125	$^\circ C$
Storage temperature		T_{STG}	-55		+150	$^\circ C$
Forward voltage	$I_F = 1$ mA	V_F			0.41	V
	$I_F = 15$ mA	V_F			1.00	V
Reverse current	$V_R = 50$ V	I_R			0.1	μA
Diode capacitance	$V_R = 0$ V, $f = 1MHz$	C_D			2.0	pF
Reverse recovery time	$I_F = I_R = 10mA$, $I_{R(Rec)} = 1.0mA$	t_{rr}			5	ns
Thermal Resistance	Junction to Ambient Air	$R_{\theta JA}$			500	$^\circ C/W$

Rating and characteristic curves for each diode (BAS70W / BAS70W-04 / BAS70W-05 / BAS70W-06)

FIG.1 Forward Characteristics

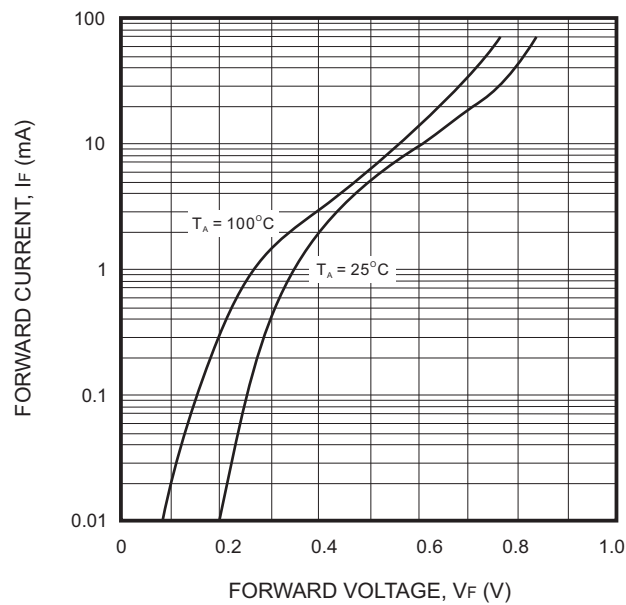


FIG.2 Reverse Characteristics

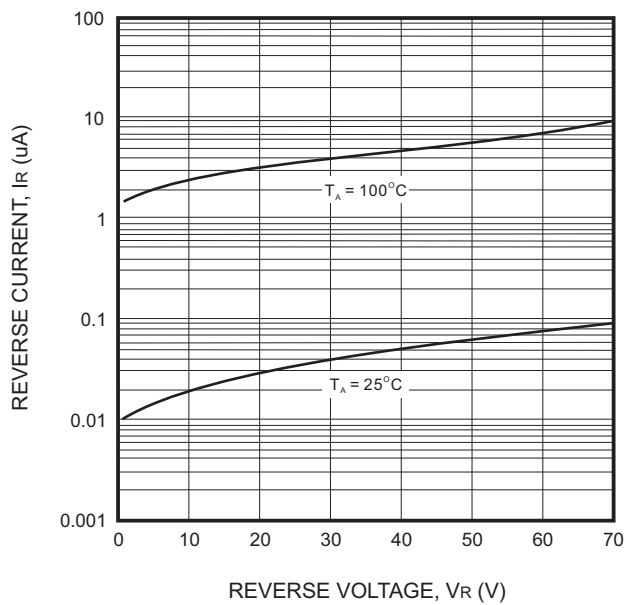


FIG.3 Power Derating Curve

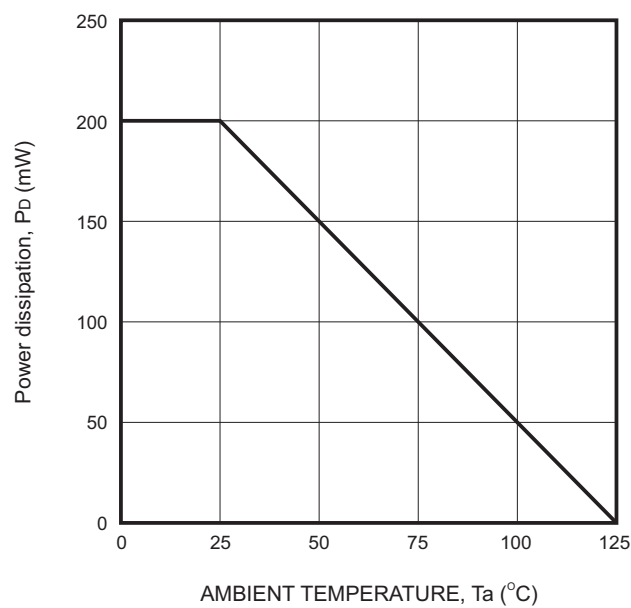
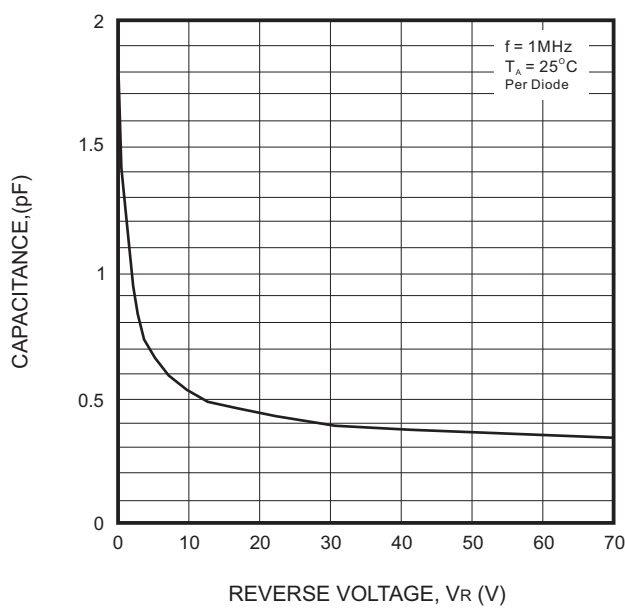
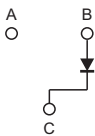
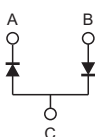
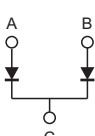
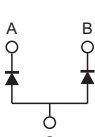


FIG.4 Capacitance Characteristics

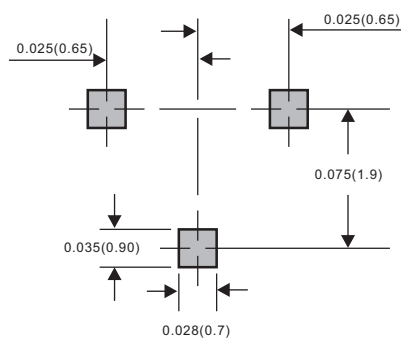


BAS70W / BAS70W-04 / BAS70W-05 / BAS70W-06**Pinning information**

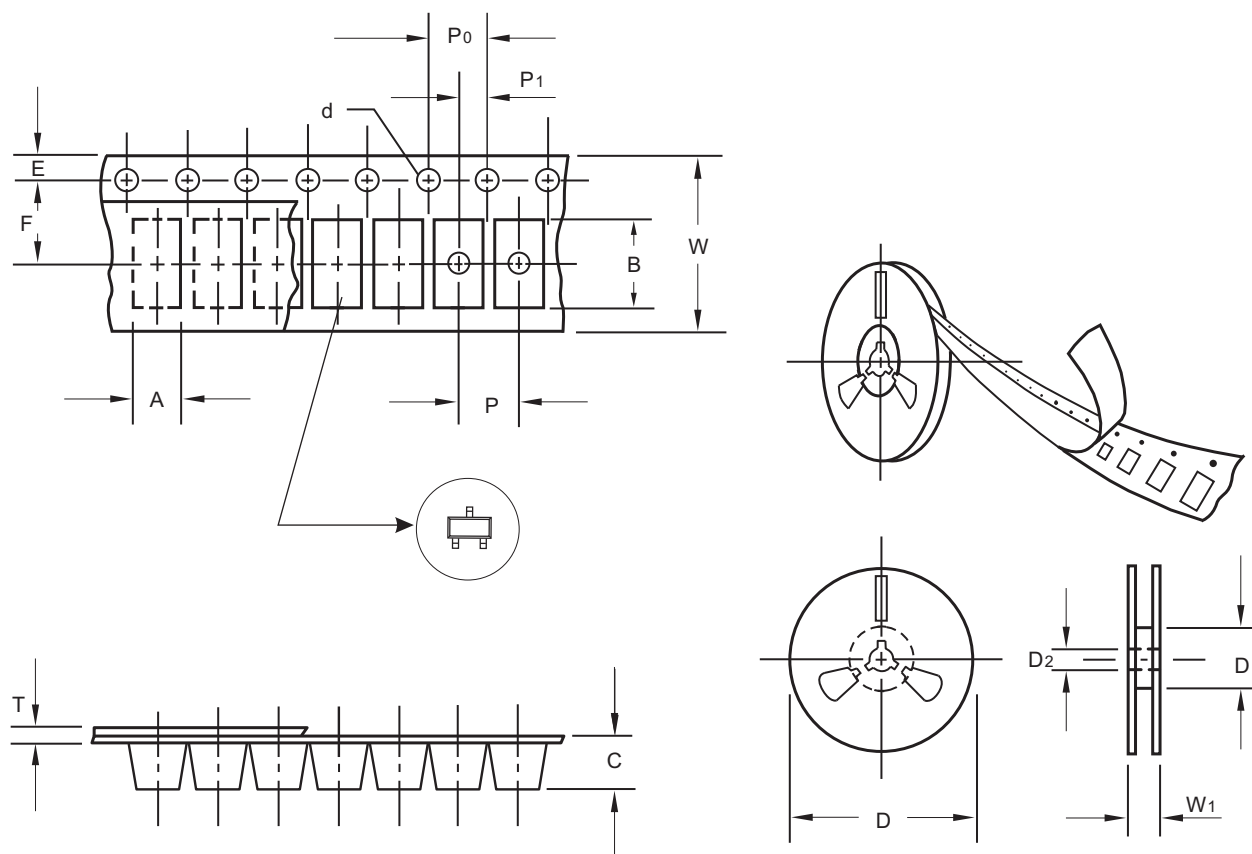
Type number	Marking code	Symbol
BAS70W	K73	
BAS70W-04	K74	
BAS70W-05	K75	
BAS70W-06	K76	

Suggested solder pad layout

SOT-323



Dimensions in inches and (millimeters)

BAS70W / BAS70W-04 / BAS70W-05 / BAS70W-06**Packing information**

unit:mm

Item	Symbol	Tolerance	SOT-323
Carrier width	A	0.1	2.36
Carrier length	B	0.1	2.40
Carrier depth	C	0.1	1.20
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	62.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W1	1.0	11.40

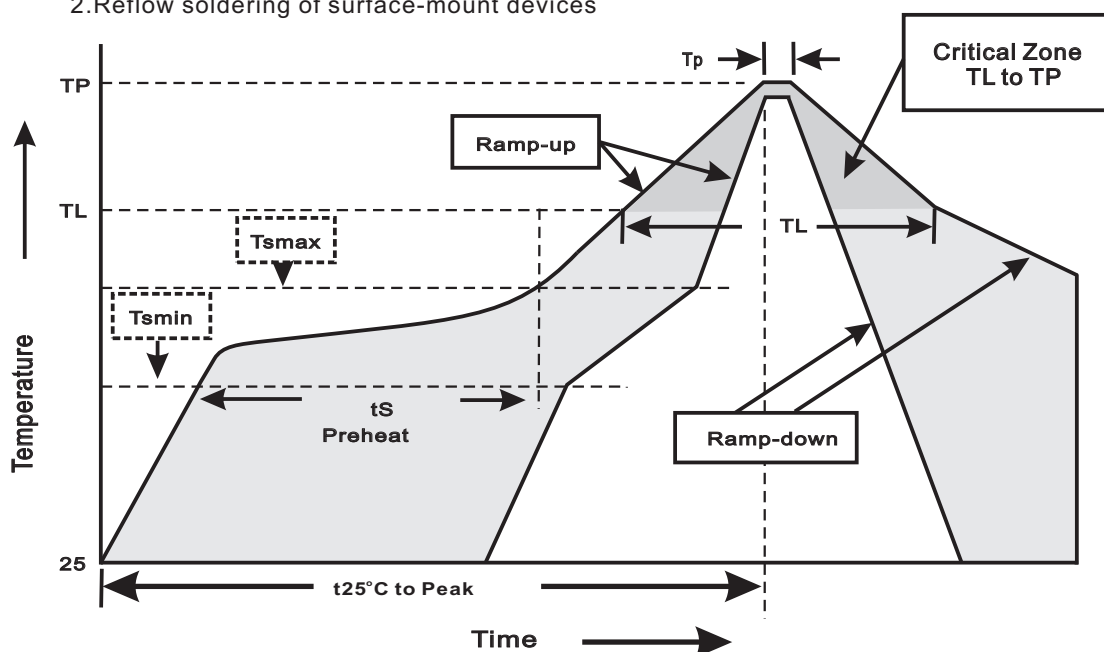
Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

BAS70W / BAS70W-04 / BAS70W-05 / BAS70W-06**Reel packing**

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOT-323	7"	3,000	4.0	30,000	183*183*123	178	382*262*387	240,000	9.5

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices

**3.Reflow soldering**

Profile Feature	Soldering Condition
Average ramp-up rate(T _L to T _P)	<3°C/sec
Preheat -Temperature Min(T _{smmin}) -Temperature Max(T _{smmax}) -Time(min to max)(t _s)	150°C 200°C 60~120sec
T _{smmax} to T _L -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T _L) -Time(t _L)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

BAS70W / BAS70W-04 / BAS70W-05 / BAS70W-06**High reliability test capabilities**

Item Test	Conditions	Reference
1. Solder Resistance	at $260 \pm 5^\circ\text{C}$ for $10 \pm 2\text{sec.}$ immerse body into solder $1/16'' \pm 1/32''$	MIL-STD-750D METHOD-2031
2. Solderability	at $245 \pm 5^\circ\text{C}$ for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_R = 80\%$ rate at $T_J = 125^\circ\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at $T_A = 25^\circ\text{C}$ for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^\circ\text{C}$, $I_F = I_O$ On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	$15P_{SIG}$ at $T_A = 121^\circ\text{C}$ for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to $+125^\circ\text{C}$ dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Thermal Shock	0°C for 5 min. rise to 100°C for 5 min. total 10 cycles.	MIL-STD-750D METHOD-1056
9. Forward Surge	Non-Repetitive Forward Current $t_p < 1\text{s}$ at $T_A = 85^\circ\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-4066-2
10. Humidity		MIL-STD-750D METHOD-1021
11. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031